

-100mA/-50V Digital transistors(with built-in resistors)

DTA043TM / DTA043TEB / DTA043TUB

Features

- Built-in input resistor enables the direct control of base terminal by input voltage without external resistor. (See Inner circuit)
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making the device design easy.

Structure

PNP epitaxial planar silicon transistor (Resistor built-in type)

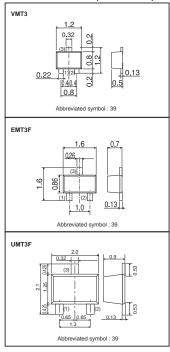
Applications

Inverter, Interface, Driver

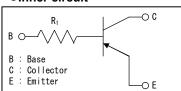
Packaging specifications

	Package	VMT3	EMT3F	UMT3F				
	Packaging Type	Taping	Taping	Taping				
Туре	Code	T2L	TL	TL				
	Basic ordering unit (pieces)	8000	3000	3000				
DTA043TM		0	-	-				
DTA043TEB		-	0	-				
DTA043TUB		-	-	0				

●Dimensions (Unit:mm)



●Inner circuit



 R_1 =4.7 $k\Omega$

●Absolute maximum (Ta=25°C)

Parameter	Symbol	Limits(DTA043T□)			Unit
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Collector-base voltage	V_{CBO}	-50			V
Collector-emitter voltage	$V_{\sf CEO}$	-50			V
Emitter-base voltage	V _{EBO} -5			mA	
Collector current	I _{C(max)}	-100			mA
Power dissipation	P_{D}	150		200	mW *
Junction temperature	Tj	150			°C
Range of storage temperature	Tstg	-55 to +150			°C

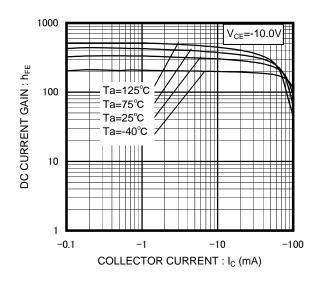
^{*} Each terminal mounted on a recommended land

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Collector-Base breakdown voltage	BV _{CBO}	-50	-	-	V	I _C =-50uA
Collector-Emitter breakdown voltage	BV_{CEO}	-50	-	-	V	I _C =-1mA
Emitter-Base breakdown voltage	BV _{CEO}	-5	-	-	V	I _E =-50uA
Collector cut-off current	I _{CBO}	-	-	-500	nA	V _{CB} =-50V
Emitter cut-off current	I _{EBO}	-	-	-500	nA	V _{EB} =-4V
Collector-Emitter saturation voltage	$V_{CE(sat)}$	-	-0.07	-0.15	V	I_C =-5mA / I_B =-0.5mA
DC current gain	h _{FE}	100	-	600	-	V_{CE} =-10V / I_{C} =-0.5mA
Transition frequency *	f _T	-	250	-	MHz	V_{CE} =-10V / I_{C} =-5mA f=100MHz
Input resistance	R ₁	3.29	4.7	6.11	kΩ	

^{*} Characteristics of built-in transistor

•Electrical characteristics curves



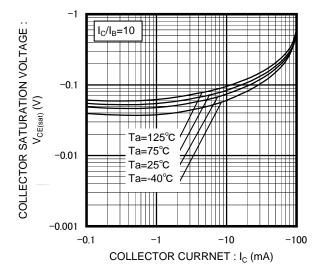


Fig.1 DC Current Gain vs. Collector Current

Fig.2 Collector Saturation Voltage vs. Collector Current

Notes

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